
**ARF463A(G)
ARF463B(G)**

 Common
Source

RF POWER MOSFETs

N-CHANNEL ENHANCEMENT MODE

125V 100W 100MHz

The ARF463A and ARF463B comprise a symmetric pair of common source RF power transistors designed for push-pull scientific, commercial, medical and industrial RF power amplifier applications up to 100 MHz. They have been optimized for both linear and high efficiency classes of operation.

- Specified 125 Volt, 81.36 MHz Characteristics:**
- Low Cost Common Source RF Package.**
- Output Power = 100 Watts.**
- Low V_{th} thermal coefficient.**
- Gain = 15dB (Class AB)**
- Low Thermal Resistance.**
- Efficiency = 75% (Class C)**
- Optimized SOA for Superior Ruggedness.**

MAXIMUM RATINGS

 All Ratings: $T_C = 25^\circ\text{C}$ unless otherwise specified.

| Symbol | Parameter | ARF463A/B(G) | UNIT |
|-----------------|---|--------------|--------------------|
| V_{DSS} | Drain-Source Voltage | 500 | Volts |
| I_D | Continuous Drain Current @ $T_C = 25^\circ\text{C}$ | 9 | Amps |
| V_{GS} | Gate-Source Voltage | ± 30 | Volts |
| P_D | Total Power Dissipation @ $T_C = 25^\circ\text{C}$ | 180 | Watts |
| $R_{\theta JC}$ | Junction to Case | 0.70 | $^\circ\text{C/W}$ |
| T_J, T_{STG} | Operating and Storage Junction Temperature Range | -55 to 150 | $^\circ\text{C}$ |
| T_L | Lead Temperature: 0.063" from Case for 10 Sec. | 300 | |

STATIC ELECTRICAL CHARACTERISTICS

| Symbol | Characteristic / Test Conditions | MIN | TYP | MAX | UNIT |
|--------------|--|-----|-----|-----------|---------------|
| BV_{DSS} | Drain-Source Breakdown Voltage ($V_{GS} = 0V, I_D = 250 \mu\text{A}$) | 500 | | | Volts |
| $V_{DS(ON)}$ | On State Drain Voltage ^① ($I_D(ON) = 4.5A, V_{GS} = 10V$) | | | 5.0 | |
| I_{DSS} | Zero Gate Voltage Drain Current ($V_{DS} = V_{DSS}, V_{GS} = 0V$) | | | 25 | μA |
| | Zero Gate Voltage Drain Current ($V_{DS} = 0.8 V_{DSS}, V_{GS} = 0V, T_C = 125^\circ\text{C}$) | | | 250 | |
| I_{GSS} | Gate-Source Leakage Current ($V_{GS} = \pm 30V, V_{DS} = 0V$) | | | ± 100 | nA |
| g_{fs} | Forward Transconductance ($V_{DS} = 25V, I_D = 4.5A$) | 4 | 6 | | mhos |
| $V_{GS(TH)}$ | Gate Threshold Voltage ($V_{DS} = V_{GS}, I_D = 50mA$) | 3 | | 5 | Volts |

 **CAUTION:** These Devices are Sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.

DYNAMIC CHARACTERISTICS

ARF463A/B(G)

| Symbol | Characteristic | Test Conditions | MIN | TYP | MAX | UNIT |
|--------------|------------------------------|--|-----|------|------|------|
| C_{iss} | Input Capacitance | $V_{GS} = 0V$ $V_{DS} = 50V$ $f = 1\text{ MHz}$ | | 1200 | 1600 | pF |
| C_{oss} | Output Capacitance | | | 140 | 200 | |
| C_{rss} | Reverse Transfer Capacitance | | | 9 | 12 | |
| $t_{d(on)}$ | Turn-on Delay Time | $V_{GS} = 15V$ $V_{DD} = 0.5 V_{DSS}$ $I_D = I_{D[Cont.]} @ 25^\circ C$ $R_G = 1.6\Omega$ | | 5.1 | 10 | ns |
| t_r | Rise Time | | | 4.1 | 8 | |
| $t_{d(off)}$ | Turn-off Delay Time | | | 12.8 | 20 | |
| t_f | Fall Time | | | 4 | 8 | |

FUNCTIONAL CHARACTERISTICS

| Symbol | Characteristic | Test Conditions | MIN | TYP | MAX | UNIT |
|----------|------------------------------------|--|--------------------------------|-----|-----|------|
| G_{PS} | Common Source Amplifier Power Gain | $f = 81.36\text{ MHz}$ | 13 | 15 | | dB |
| η | Drain Efficiency | $I_{dq} = 50\text{mA}$ $V_{DD} = 125V$ | 60 | 65 | | % |
| Ψ | Electrical Ruggedness VSWR 10:1 | $P_{out} = 100W$ | No Degradation in Output Power | | | |

① Pulse Test: Pulse width < 380 μs , Duty Cycle < 2%

APT Reserves the right to change, without notice, the specifications and information contained herein.

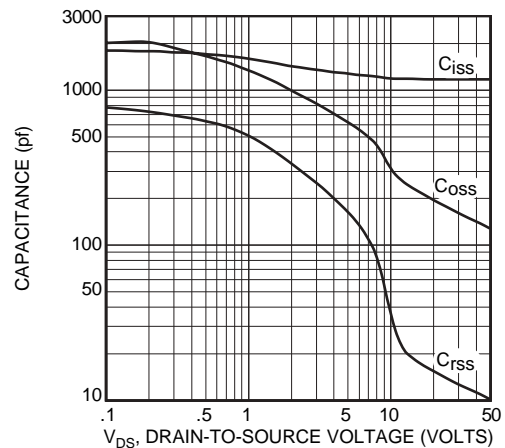


Figure 2, Typical Capacitance vs. Drain-to-Source Voltage

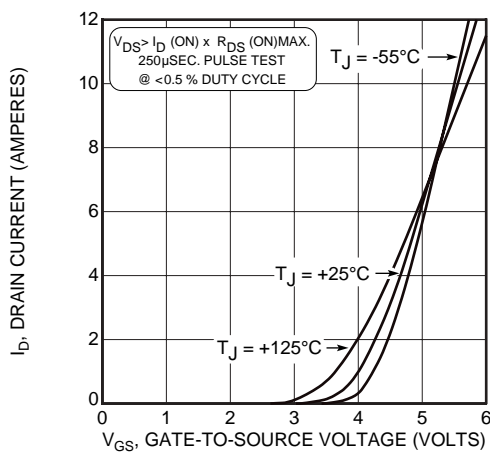


Figure 3, Typical Transfer Characteristics

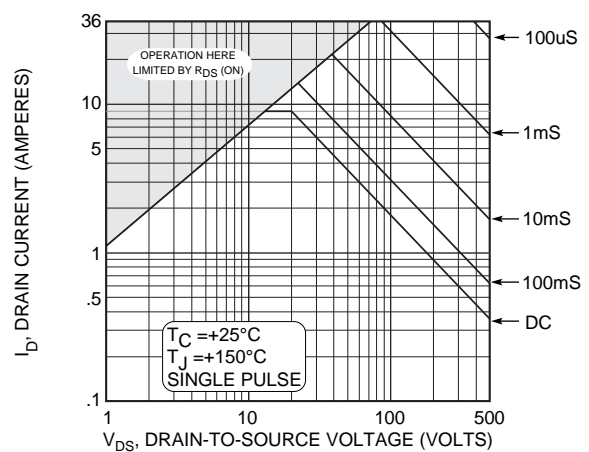


Figure 4, Typical Maximum Safe Operating Area

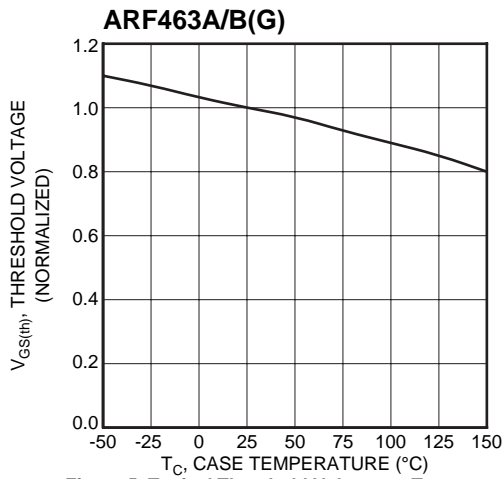


Figure 5, Typical Threshold Voltage vs Temperature

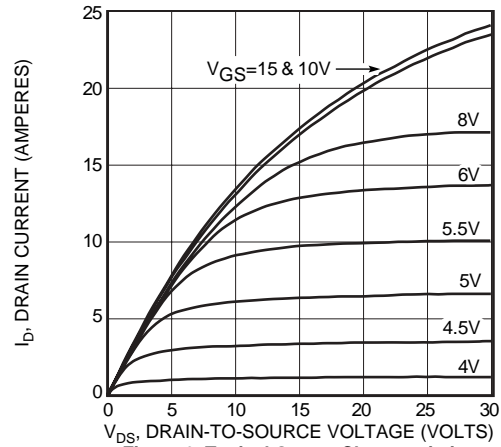


Figure 6, Typical Output Characteristics

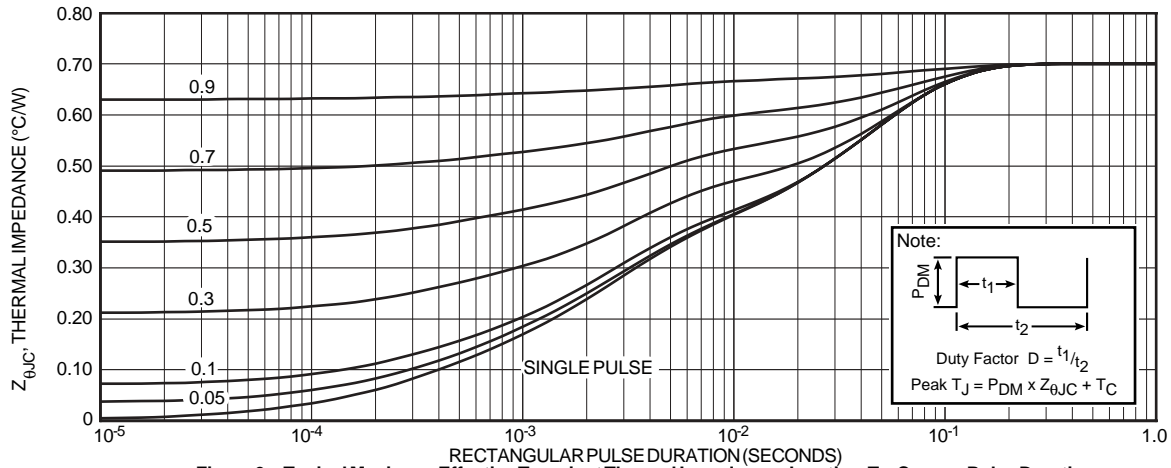


Figure 9a, Typical Maximum Effective Transient Thermal Impedance, Junction-To-Case vs Pulse Duration

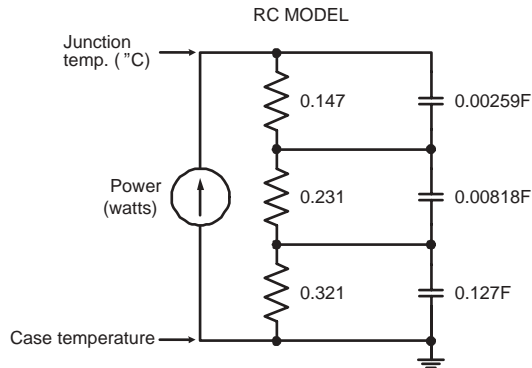


Figure 9b, TRANSIENT THERMAL IMPEDANCE MODEL

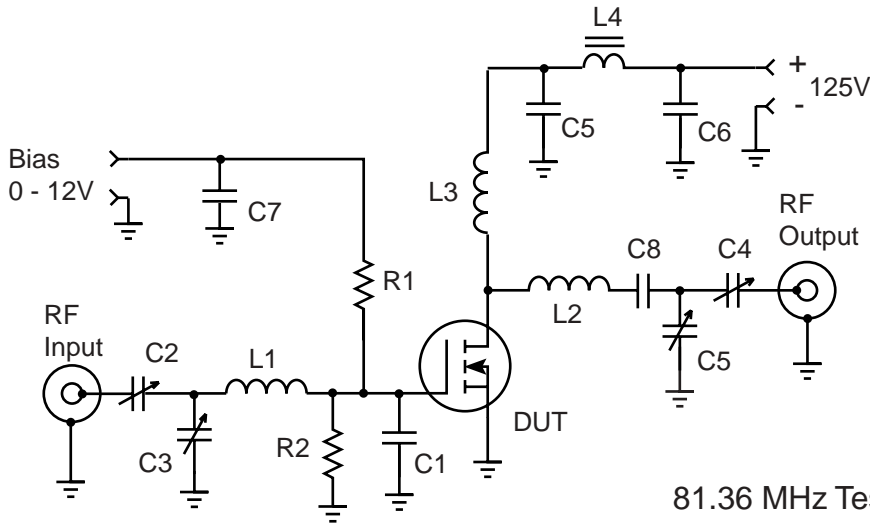
Table 1 - Typical Class AB Large Signal Input - Output Impedance

| Freq. (MHz) | Z _{in} (Ω) | Z _{OL} (Ω) |
|-------------|---------------------|---------------------|
| 2.0 | 24 - j 5.0 | 55 - j 4.8 |
| 13.5 | 7.8 - j 11 | 41 - j 24 |
| 27 | 2.1 - j 6.4 | 23 - j 26.2 |
| 40 | .74 - j 3.3 | 13.6 - j 22 |
| 65 | .30 + j .42 | 6.1 - j 14.2 |
| 80 | .46 + j 2.0 | 4.2 - j 10.7 |
| 100 | .87 + j 3.7 | 2.7 - j 7.1 |

Z_{in} - Gate shunted with 25Ω

I_{DQ} = 50mA

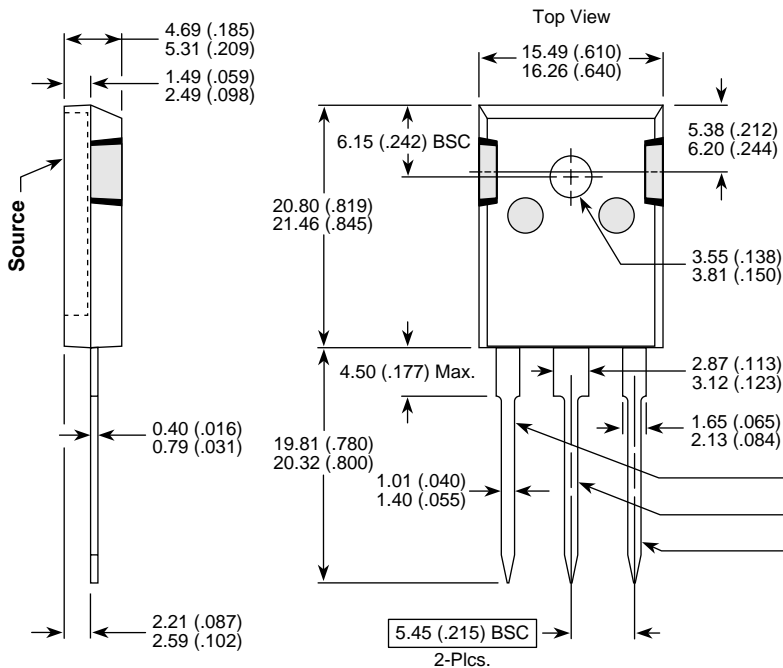
Z_{OL} - Conjugate of optimum load for 100 Watts output at V_{DD} = 125V



- C1 -- 820pF Unelco mounted at gate lead
- C2-C5 -- Arco 463 Mica trimmer
- C5-C8 -- 10nF 500V COG chip
- L1 -- 3t #18 .3" ID .25"L ~50nH
- L2 -- 3t #16 AWG .25" ID .3"L ~58nH
- L3 -- 10t #18 AWG .25 ID ~470nH
- L4 -- VK200-4B ferrite choke ~3uH
- R1-R2 -- 50 Ohm 1/2W Carbon
- DUT = ARF463A/B

81.36 MHz Test Circuit

TO-247 Package Outline



HAZARDOUS MATERIAL WARNING

The ceramic portion of the device between leads and mounting surface is beryllium oxide, BeO. Beryllium oxide dust is toxic when inhaled. Care must be taken during handling and mounting to avoid damage to this area. These devices must never be thrown away with general industrial or domestic waste.

Dimensions in Millimeters and (Inches)

NOTE: These two parts comprise a symmetric pair of RF power transistors and meet the same electrical specifications. The device pin-outs are the mirror image of each other to allow ease of use as a push-pull pair.

| Device | |
|---------|---------|
| ARF - A | ARF - B |
| Gate | Drain |
| Source | Source |
| Drain | Gate |

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